Ref #	Hits	Search Query	DBs	Default Operator	Plurals	Time Stamp
L1	362597	semiconductor and (image or photo$8)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/07/06 17:14
L2	127392	1 and (stor$3 or accumulat$3)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/07/06 17:15
L3	17501	2 and (gate adj electrode)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/07/06 17:15
L4	11603	3 and drain and channel	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/07/06 17:16
L5	5615	4 and overlap$5	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/07/06 17:17
L6	4376	5 and (charg$3 or carrier)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/07/06 17:17
L7	1468	6 and barrier	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/07/06 17:18